



### **60V N-Channel Enhancement Mode MOSFET**

Voltage

60 V

Current

45 A

#### **Features**

- $\bullet \ R_{DS(ON)}, \, V_{GS}@10V, \, I_D@20A{<}12m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@15A<15m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard



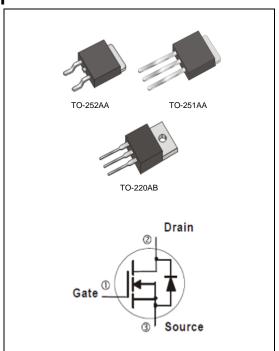
• Case: TO-251AA,TO-252AA,TO-220AB Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-251AA Approx. Weight: 0.0104 ounces, 0.297grams

• TO-252AA Approx. Weight: 0.0104 ounces, 0.297grams

• TO-220AB Approx. Weight: 0.067 ounces, 1.9 grams



# Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	TO-252AA	UNITS
Drain-Source Voltage		$V_{DS}$	60			V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20			
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	I <sub>D</sub>	45	55	45	A
	T <sub>C</sub> =100°C		29	35	29	
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	180	220	180	
Power Dissipation	T <sub>C</sub> =25°C	PD	63	96	63	W
	T <sub>C</sub> =100°C		25	38	25	
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	61			mJ
Operating Junction and		$T_{J}$ , $T_{STG}$	-55~150			°C
Storage Temperature Range						
Typical Thermal Resistance (Note 4,5)						
- Junction to Case		$R_{ heta JC}$	2.0	1.3	2.0	°C/W
- Junction to Ambient		$R_{ heta JA}$	110	62.5	110	
Limited only By Maximum Junction Temperature						

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# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1	1.7	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =10V, $I_D$ =20A	-	10.5	12	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A	-	12	15	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	Qg	V <sub>DS</sub> =30V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V <sup>(Note 2,3)</sup>	-	39	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	6.1	-	
Gate-Drain Charge	$Q_{gd}$		-	6.7	-	
Input Capacitance	Ciss	V 05V V 0V	-	2256	-	pF
Output Capacitance	Coss	$V_{DS}$ =25V, $V_{GS}$ =0V, f=1.0MHZ	-	145	-	
Reverse Transfer Capacitance	Crss	I=1.UIVIDZ	-	93	-	
Turn-On Delay Time	td <sub>(on)</sub>	\\ A5\\   A0A	-	7.5	-	ns
Turn-On Rise Time	t <sub>r</sub>	V <sub>DD</sub> =15V, I <sub>D</sub> =10A,	-	36	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}=10V, R_{G}=6\Omega$ (Note 2.3)	-	49	-	
Turn-Off Fall Time	t <sub>f</sub>		-	12	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	45	А
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.67	1	V

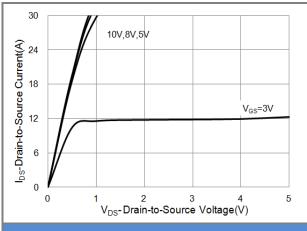
#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$ =25°C.
- 4. The maximum current rating is package limited.
- 5. ROJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH,  $I_{AS}$ =35A,  $V_{DD}$ =25V,  $V_{GS}$ =10V
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**



**Fig.1 Output Characteristics** 

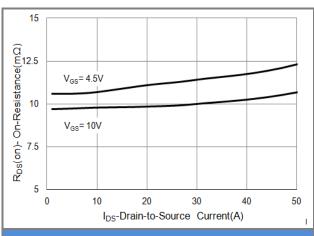
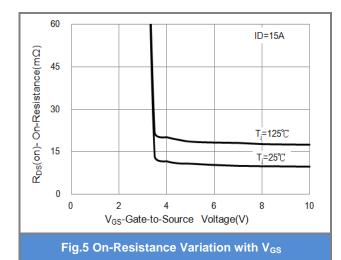


Fig.3 On-Resistance vs. Drain Current



**Fig.2 Transfer Characteristics** 

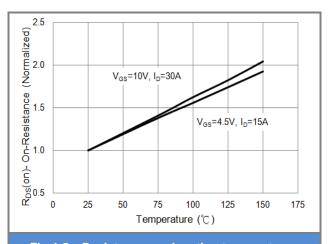
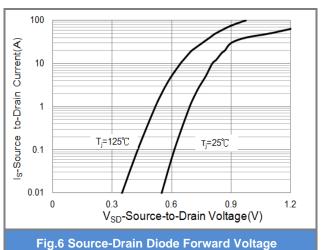


Fig.4 On-Resistance vs. Junction temperature



i ig.o Source-Drain Diode i orward voltage





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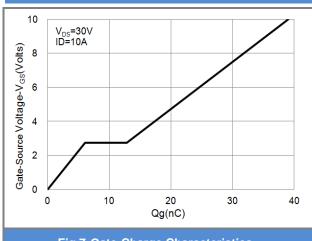


Fig.7 Gate-Charge Characteristics

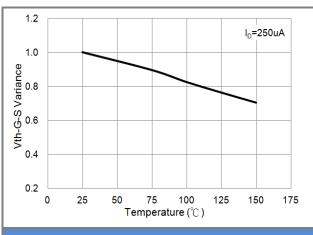
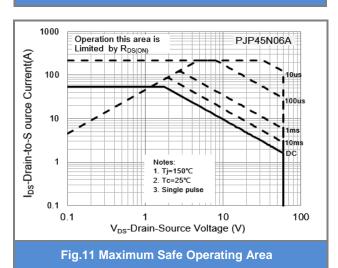


Fig.9 Threshold Voltage Variation with Temperature



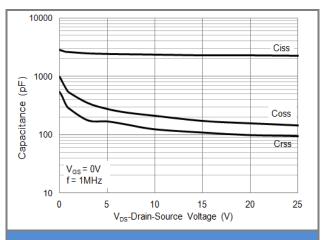


Fig.8 Capacitance vs. Drain-Source Voltage

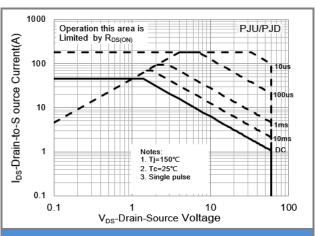


Fig.10 Maximum Safe Operating Area





#### TYPICAL CHARACTERISTIC CURVES

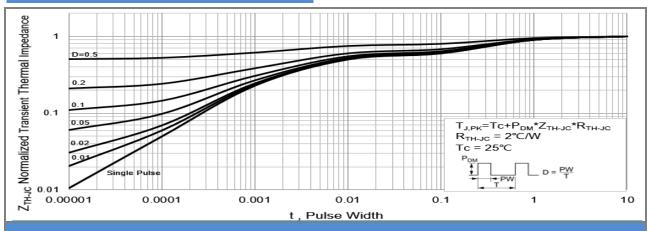


Fig.12 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

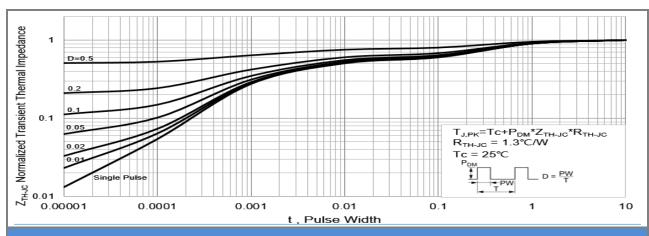
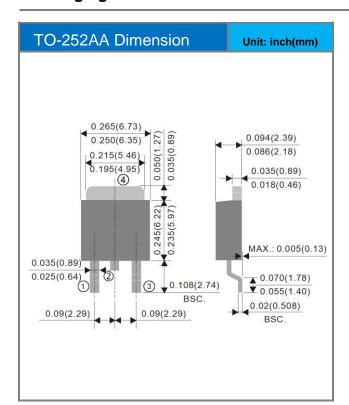


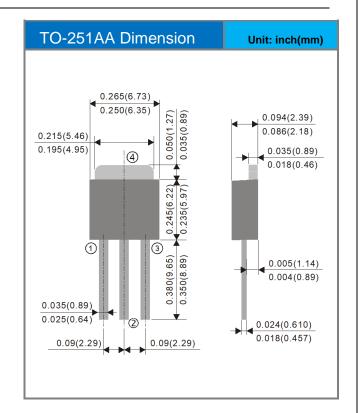
Fig.13 Normalized Transient Thermal Impedance vs. Pulse Width

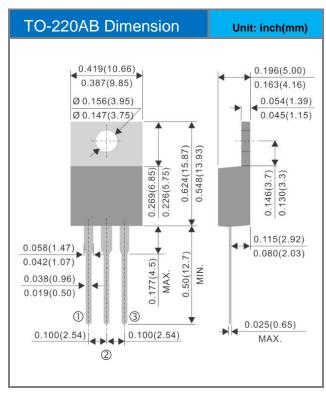




#### **Packaging Information**







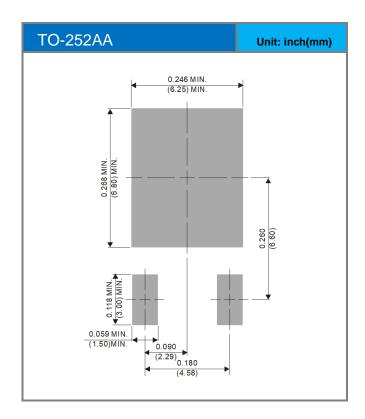




### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU45N06A_T0_00001	TO-251AA	80pcs / Tube	U45N06A	Halogen free
PJD45N06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D45N06A	Halogen free
PJP45N06A_T0_00001	TO-220AB	50pcs / Tube	P45N06A	Halogen free

### **Mounting Pad Layout**







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